

Synthesis and Crystal Structure of Nb_{0.84}N

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A new compound of the composition Nb_{0.84}N was prepared by ammonolysis of NbO₂ at 1100 °C. The crystal structure refinement was performed by the Rietveld method using X-ray and neutron powder diffraction data. Nb_{0.84}N crystallizes in the trigonal space group $R\bar{3}m$ (no. 166) with the lattice parameters $a = 298.5(2)$ and $c = 2384.3(4)$ pm. The niobium atoms form a close packing with a layer sequence which can be described by the Jagodzinski symbol hhc . The nitrogen atoms fill all octahedral voids. Along [001] a sequence of two layers of trigonal NbN₆ prisms and one layer of NbN₆ octahedra is formed. The nitrogen positions are fully occupied, the niobium positions only partially. Nb_{0.84}N is part of a family of crystal structures between the *anti*-NiAs and the NaCl type consisting of close-packed metal layers with varying stacking sequences.

Key words: Niobium Nitride, Synthesis, Neutron Powder Diffraction, Close Packing

Introduction

Metal nitrides are of increasing interest because of their unique chemical and physical properties. Today they are used in applications ranging from refractory ceramics and wear-resistant coatings to semiconductor devices for optoelectronics [1, 2].

A number of niobium nitrides where niobium is surrounded either by octahedra or by trigonal prisms of nitrogen atoms is known from the literature since the early works of Brauer, Jander, and Esselborn [3–7]. For example, δ -NbN crystallizes in the NaCl type, and γ -NbN forms a tetragonal superstructure of the NaCl type [5]. Both phases are slightly deficient in nitrogen. δ -NbN_{0.95} crystallizes in the NiAs type where the nitrogen atoms form a hexagonal close packing, while in ε -NbN the nitrogen atoms form a close packing with a stacking sequence of hhc [7]. In all these compounds Nb is octahedrally coordinated by nitrogen atoms.

On the other hand, δ' -Nb_{0.95}N crystallizes in the *anti*-NiAs type where nitrogen atoms form layers of prisms which are filled with Nb or remain empty [5–7]. Nb₂N also exhibits the *anti*-NiAs type, but the position of N is only half occupied [5, 6]. While in the *anti*-NiAs type filled and empty prisms alternate in neighboring layers, in Nb_{0.9}N and NbN_{0.85} the filled prisms lie above each other in every layer [5, 6]. Tetragonal

Nb₄N₅ shows a defect NaCl-type structure with niobium vacancies [8, 9]. Finally, Nb₅N₆ should be mentioned which consists of alternating layers of NbN₆ octahedra (only partially filled) and NbN₆ prisms [8]. As shown by the above-mentioned compositions, niobium nitrides can be deficient both of nitrogen (NbN_{1-x}) and of niobium (Nb_{1-y}N). In this contribution we present a new niobium nitride synthesized by ammonolysis of niobium(IV) oxide at high temperatures.

Experimental Section

An alumina boat containing 2 g niobium(IV) oxide (Alfa Aesar, 99+ % metal base) was placed in an alumina tube inside a horizontal tube furnace (Gero F 70-500). The new compound was obtained by reaction of NbO₂ with water-saturated ammonia gas at 1100 °C for 76 h. The flow rate was 10 L h⁻¹. This procedure resulted in a grey powder with a silvery gloss. Nitrogen and oxygen contents were determined using a LECO TC-300 / EF-300 N/O analyzer (hot gas extraction). The accuracy (relative uncertainty) is about 2 % of the N/O present.

As the new phase was only obtained as a powder, powder diffraction methods were used to determine the crystal structure. Diffraction experiments were performed with a Siemens D5000 diffractometer (Bragg-Brentano geometry, CuK α 1 radiation, $\lambda = 154.06$ pm, position sensitive detector) at r. t. The sample was fixed on a flat silicon sample holder.

As the positions of the nitrogen atoms were difficult to refine in the presence of the heavier niobium atoms using X-ray methods, a neutron powder diffraction experiment was performed. Neutron diffraction patterns were recorded using the neutron powder diffractometer E6 at the BERII reactor of the Helmholtz-Zentrum Berlin für Materialien und Energie. The incident neutron wavelength was 244.6 pm. The area detector of the instrument covers an angular range of $2\theta = 18 - 105^\circ$. The sample container was a vanadium cylinder with a diameter of 6 mm. All data were collected at r. t. (293 K).

Temperature-dependent X-ray diffraction measurements (samples in SiO₂-glass capillaries under nitrogen) were carried out using a Stoe STADI-P powder diffractometer (MoK α_1 radiation, $\lambda = 70.93$ pm, imaging plate detector) with a graphite heated resistance furnace.

Results and Discussion

By reaction with water-saturated ammonia gas at 1100 °C a new niobium nitride was synthesized. Temperature-dependent X-ray powder diffraction measurements have clearly shown that the new phase is stable at least up to 1000 °C (Fig. 1).

N/O analysis of the obtained powder showed 15.2 mass-% (m-%) nitrogen and 0.47 m-% oxygen. Rietveld refinements of the powder diffraction data pointed to the presence of two impurity phases. The minor impurity phase (~ 3.5 m-%) shows a diffraction pattern similar to that of a NbN phase only known from thin films [11]. It can be assumed that due to the small content of this phase it is stabilized by the matrix. The major impurity phase (~ 8.8 m-%) has a lattice

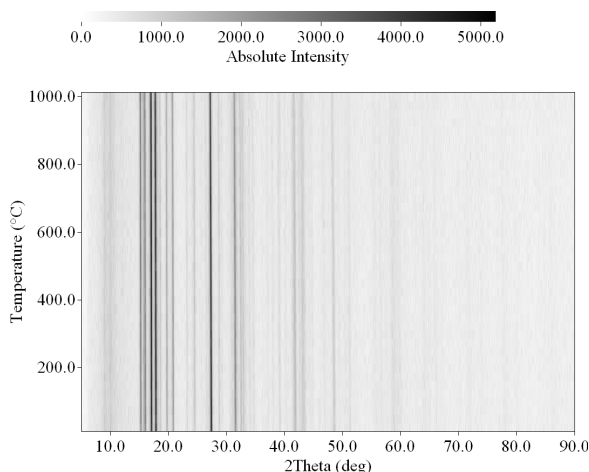


Fig. 1. Temperature-dependent X-ray powder diffraction patterns of Nb_{0.84}N (MoK α_1 radiation, wavelength 70.93 pm) up to 1000 °C. The sample remains stable over the entire temperature range.

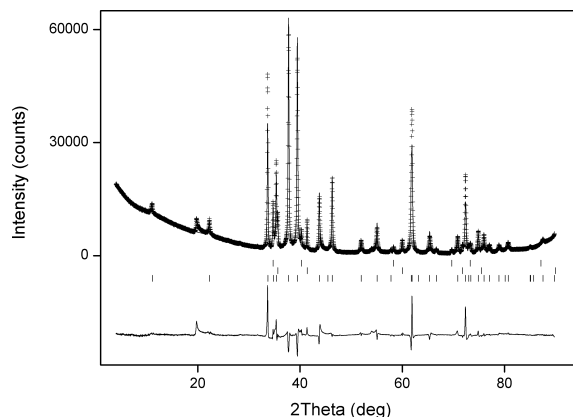


Fig. 2. Observed (crosses) and calculated (line) X-ray powder diffraction patterns of Nb_{0.84}N (CuK α_1 radiation, wavelength 154.06 pm) and difference profiles of the Rietveld refinement. The lower row of vertical lines gives possible peak positions, the upper rows those of NbN_{0.71}O_{0.23} and NbN, respectively.

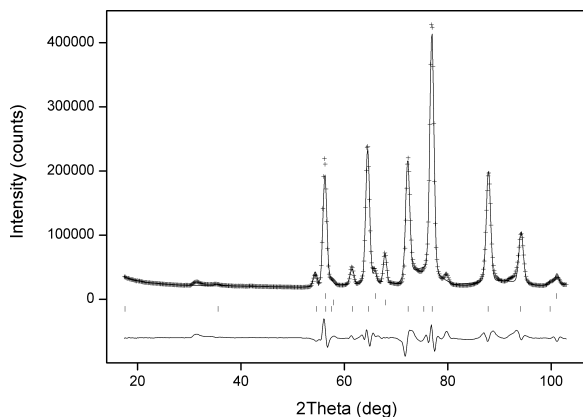
constant of 436.5 pm, which lies between the values of NbN_{0.43}O_{0.42} (434.3 pm [12]) and of NbN_{0.9}O_{0.1} (438.2 pm [7]). Therefore a composition of about NbN_{0.71}O_{0.23} is estimated for this impurity. Respecting these phases for the calculation of the stoichiometry of the main phase, an Nb : N ratio of $\sim 0.75 : 1$ is found.

The main phase of the obtained diffraction patterns (Fig. 2) can be indexed with a rhombohedral unit cell with a small a and a large c lattice parameter, 298.5(2) and 2384.3(4) pm, respectively (hexagonal setting). A search in the literature revealed three compounds with similar lattice constants and the rhombohedral space group $R\bar{3}m$ (η -Ti₃N_{1.29} [13], η -Hf₃N₂ [14, 15], Th₃N₄ [16]). Because η -Hf₃N₂ has lattice constants closest to the new phase, its atomic coordinates were used as input for the Rietveld refinement (program GSAS [17]).

As discussed below in detail, the crystal structure contains two non-equivalent Nb atoms, one being octahedrally coordinated by nitrogen, and the other surrounded by six nitrogen atoms forming a trigonal prism. Refinements of the site occupation factors (X-ray data) have indicated that the sites of the niobium atoms are not fully occupied. When the occupation of the N positions was fixed at 100 %, the site occupation factor of the octahedral position of niobium was found to be smaller ($x = 0.65(1)$) than that of the position surrounded by a trigonal prism ($x = 0.94(1)$). From these results the composition of the new compound was calculated to \sim Nb_{0.87}N. This is in

Table 1. Crystallographic data for Nb_{0.84}N.

	Neutron data	X-Ray data
M_r , g mol ⁻¹	92.05	92.36
Crystal system	— trigonal —	
Space group	— $R\bar{3}m$ (no. 166) —	
Radiation; λ , pm	neutrons; 244.6	CuK α_1 ; 154.06
Temperature, °C	~ 22	~ 22
Lattice constants		
a , pm	298.5(2)	299.49(1)
c , pm	2384.3(4)	2392.2(1)
V , $\times 10^6$ pm ³	184.01(17)	185.82(1)
Z	9	
ρ_{calcd} , g cm ⁻³	7.47	7.43
Profile range, deg	$3 \leq 2\theta \leq 105$	$5 \leq 2\theta \leq 90$
R values		
wR_p	0.084	0.120
R_p	0.061	0.066
R_F^2	0.035	0.143

Fig. 3. Observed (crosses) and calculated (line) neutron powder diffraction patterns (wavelength 244.6 pm) and difference profiles of the Rietveld refinement of Nb_{0.84}N. The lower row of vertical lines gives possible peak positions, the upper rows those of NbN_{0.71}O_{0.23} and NbN, respectively.

fair agreement with the stoichiometric formula derived from N/O analysis which gave Nb_{0.75}N.

Refinement of the neutron powder diffraction data (Fig. 3) confirmed the results of the X-ray diffraction experiments. For this method, the site occupation factors are $x = 0.62(1)$ for the octahedral position and $x = 0.95(1)$ for the trigonal prismatic position. Thus the composition can be calculated to $\sim \text{Nb}_{0.84}\text{N}$. As the position and site occupation of nitrogen is more accurate for the neutron diffraction data than for the X-ray data, as of now we will refer to the composition of the new phase as Nb_{0.84}N. Crystallographic data are summarized in Table 1, the atomic coordinates from the neutron powder diffraction experiment are listed in Table 2, and bond lengths and angles in Table 3.

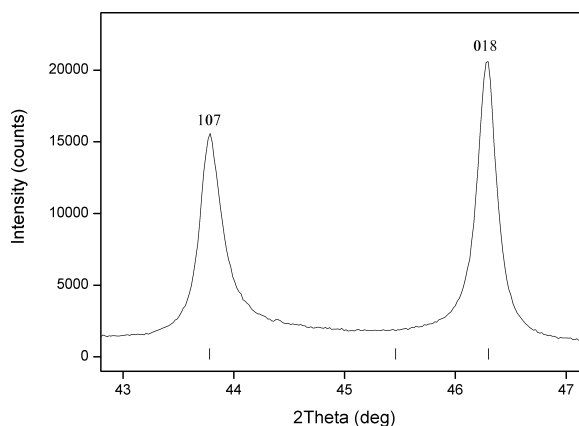
Table 2. Atomic positions, isotropic displacement parameters^a (pm²) and site occupation factors SOF for Nb_{0.84}N (neutron data).

Atom	W.-position	x	y	z	U_{iso}	SOF
Nb1	3a	0	0	0	239(39)	0.62(1)
Nb2	6c	0	0	0.2255(2)	290(33)	0.95(1)
N1	3b	0	0	1/2	248(28)	1
N2	6c	0	0	0.3870(1)	310(43)	1

^a U_{iso} is defined as $\exp[-8\pi^2 U(\sin^2 \theta / \lambda^2)]$.

Table 3. Bond lengths (pm) and angles (deg) for Nb_{0.84}N (neutron data).

Nb1–Nb2	211.8(1)	6×	N2–Nb1–N2	90.28(1)	6×
Nb2–Nb1	223.3(1)	3×	N2–Nb1–N2	89.72(1)	6×
Nb2–Nb2	221.1(1)	3×	N2–Nb1–N2	180	3×
			N2–Nb2–N2	84.49(1)	6×
			N2–Nb2–N2	77.44(1)	3×
			N1–Nb2–N2	134.07(1)	6×

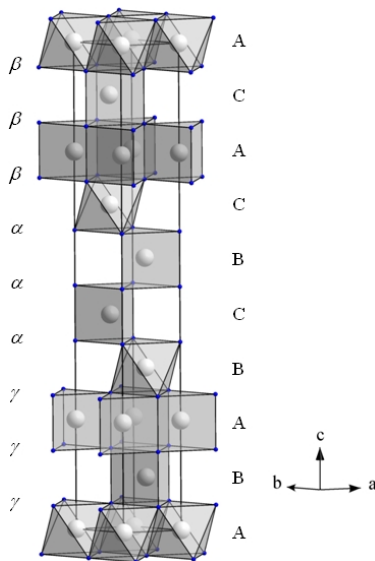
Fig. 4. Detail of the X-ray diffraction pattern of Nb_{0.84}N showing the asymmetric peak shape of a reflection with an index of the 10(3n + 1) type (diffraction band to higher diffraction angles) and one with an index of the 01(3n + 2) type (diffraction band to lower diffraction angles), respectively.

During refinement some deviations between calculated and observed intensities were detected for some of the diffraction peaks. At closer examination the peaks with indices 10(3n + 1) and 02(3n + 1) show a diffraction band (“tailing”) to higher diffraction angles, while, in contrast, the peaks with indices 01(3n + 2) and 20(3n + 2) show a diffraction band to lower diffraction angles (Fig. 4). This is caused by stacking faults which can not be accounted for by common Rietveld refinement programs.

The new compound described here consists of close-packed Nb layers, the packing sequence along the c axis being ABABCBCACA or $(hbc)_3$ after Jagodzinski [18]. The N atoms form the non-close-packed se-

Table 4. Members of the NiAs-NaCl and *anti*-NiAs-NaCl families; *n* is the number of close-packed layers in the unit cells.

NiAs-NaCl family	<i>anti</i> -NiAs-NaCl family	Jagodzinski notation	<i>n</i>	Space group
NiAs [20], TiS [21] <i>etc.</i>	δ' -Nb _{0.95} N [10], PtB [22]	h_2	2	$P6_3/mmc$
TiP [24], Ti ₃ S ₄ [33], ϵ -NbN [7], HfP [31], TiAs [32]	Ta ₃ MnN ₄ [23], ScNbN _{1-x} [25], ScTa _{1-x} N [26], BaCeN ₂ [27], Li _{0.84} W _{1.16} N ₂ [28], TlInS ₂ -III [29], CsPrS ₂ -II [30]	$(hc)_2$	4	$P6_3/mmc$
Ti ₃ SiC ₂ [35]	η -Mo ₃ C ₂ [34]	$(hcc)_2$	6	$P6_3/mmc$
Ti _{5.36} S ₈ [37]	—	$hhchcchc$	8	$P\bar{3}m1$
TiS-9R [37], Zr _{2.29} Te ₂ As [38], NaZr ₂ Te ₂ As [38]	η -Ti ₃ N _{1.29} [13], η -Hf ₃ N ₂ [14], Ta ₂ VC ₂ [36], Nb _{0.84} N	$(hhc)_3$	9	$R\bar{3}m$
Ti ₄ S ₅ [46]	—	$(hhchc)_2$	10	$P6_3/mmc$
Ti _{7.5} S _{12-12R} [41], TiS _{1.71} [42], Sc ₂ Te ₃ [43], FeIn ₂ S ₂ Se ₂ [44], Li _{0.62} CoO ₂ [45]	ζ -V ₄ C _{2.66} [39], ζ -Hf ₄ N ₃ [14], ζ -Ti ₄ N _{2.333} [40]	$(hhcc)_3$	12	$R\bar{3}m$

Fig. 5. Crystal structure of Nb_{0.84}N. Partially filled sites are shown fully occupied, and coordination polyhedra around the metals (balls) are given. A, B, and C denote layers of the niobium atoms, α , β , and γ layers of nitrogen atoms.

quence $\gamma\gamma\alpha\alpha\beta\beta\beta$ (Fig. 5). As a consequence, layers of edge-sharing NbN₆ octahedra alternate with two layers of NbN₆ edge-sharing prisms. Both sorts of layers are connected *via* edges. Fig. 6 shows the coordination polyhedra around the two sorts of Nb, and in Table 2 some interatomic distances and angles are listed. The distances Nb–N of 212, 223, and 221 pm are in good agreement with values for typical Nb–N distances of 210 to 230 pm given in the Inorganic Crystal Structure Database ICSD [19].

Nb_{0.84}N is part of a family of compounds with crystal structures derived from both the *anti*-NiAs and the NaCl type. These compounds consist of close-packed metal atoms with varying stacking sequences with anions in all octahedral voids. The coordination polyhe-

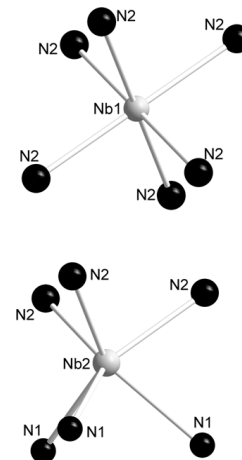


Fig. 6. Coordination polyhedra around Nb1 and Nb2. Nb1 is octahedrally coordinated by six N atoms, Nb2 by six N atoms forming a trigonal prism.

dra around the metals are trigonal prisms or octahedra which are arranged in layers of exclusively one type of these polyhedra. All types of this family can also be described as *anti*-types of the family of compounds between the NiAs- [20] and NaCl-type structures. For this second family the packing of anions is closest, and only layers of octahedra around the cations are stacked. Table 4 lists some examples of both families. Fig. 7 shows some of these structures in comparison to that of Nb_{0.84}N. The simplest stacking sequence is observed for the NiAs type with about 60 known members (mainly pnictides and chalcogenides like TiS [21]) and the *anti*-NiAs type with δ -NbN [10] and PtB [22]. The Ta₃MnN₄ type [23] is equivalent with the *anti*-TiP type [24], the packing of the metals being $(hc)_2$. There are other nitrides with this type (ScNbN_{1-x} [25], ScTa_{1-x}N [26], BaCeN₂ [27], and Li_{0.84}W_{1.16}N₂ [28]), but also sulfides (TlInS₂-III [29], CsPrS₂-II [30]) crystallize in this form. The TiP type is known for a

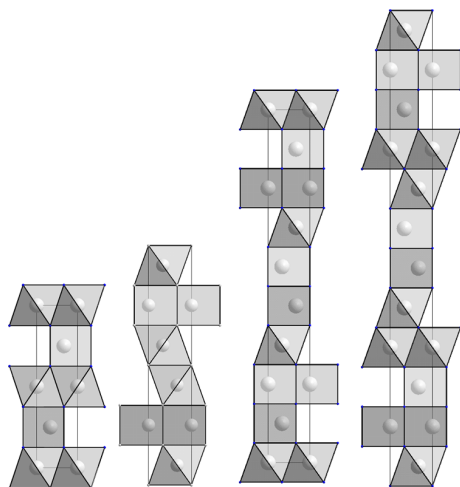


Fig. 7. Unit cells of Ta₃MnN₄ [23], η-Mo₃C₂ [34], Nb_{0.84}N, and ζ-Hf₄N₃ [14]. Partially filled sites are shown fully occupied. Coordination polyhedra around the metals (balls) are given.

number of pnictides [7, 31, 32] and for titanium sulfide Ti₃S₄ [33]. In η-Mo₃C₂ [34], which forms the *anti*-type to the Ti₃SiC₂ type [35], the packing of the metals is (*hcc*)₂. The title compound Nb_{0.84}N crystallizes in the same stacking variant as η-Hf₃N₂ [14, 15] with the stacking period (*hhc*)₃, but with different defects. Ta₂VC₂ [36] and the high-temperature subnitride η-Ti₃N_{1.29} [13] crystallize in the same stacking variant, whereas TiS-9R forms the *anti*-type [35]; isotypic with the latter are Zr_{2.29}TeAs and NaZr₂Te₂As [38]. In ζ-V₄C₃ [39], ζ-Hf₄N₃ [14], and ζ-Ti₄N_{2.333} [40]

the metals show the close-packing variant (*hhcc*)₃, and therefore two layers of prisms alternate with two layers of octahedra. The *anti*-type is Ti_{7.5}S_{12-12R}, and some other examples are listed in Table 4 [41–45]. No *anti*-types were found for the Ti_{5.36}S₈ type [37] (*hhchcchc*), for Ti₄S₅ [46] ((*hhchc*)₂), Ti_{6.9}S_{9-18H} [47] and all stacking sequences of Ti_{1-x}S with higher complexity, which are not listed here.

In both type- and *anti*-type-families a partial occupation of the anion or metal sites is often observed. From titanium sulfides it is known that completely and partially occupied metal layers occur, which can be described by occupation waves [46]. Maxima of these waves are near *h*-packed layers, and therefore their metal content increases with increasing proportions of *h*-packed layers. In carbides crystallizing in *anti*-types of titanium sulfides (*c*-packed layers of the metal atoms) the carbon positions are fully occupied while every *h*-packed layer is half occupied. Within the group of nitrides no such trend is seen.

As mentioned above, Th₃N₄ has similar lattice parameters and the same space group as the title compound. In contrast to trigonal prisms, which are the basic building units in Nb_{0.84}N, it exhibits single-capped trigonal prisms [16]. Refinements of the title compound starting with the atomic positions of Th₃N₄ were not successful. Therefore no isotypism of the two compounds can be assumed.

Magnetic, electric, or mechanical properties have not been determined yet, because the new compound could not be synthesized without impurities.

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